



	TS112N	Units
Load Voltage	350	V
Load Current	120	mA
Max R <sub>ON</sub>	20	Ω

### Features

- Small 8 Pin SOIC Narrow Package
- Low Drive Power Requirements (TTL/CMOS Compatible)
- No Moving Parts
- High Reliability
- Arc-Free With No Snubbing Circuits
- 1500V<sub>RMS</sub> Input/Output Isolation
- FCC Compatible
- VDE Compatible
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable
- Tape & Reel Version Available

### Applications

- Telecommunications
  - Telecom Switching
  - Tip/Ring Circuits
  - Modem Switching (Laptop, Notebook, Pocket Size)
  - Hookswitch
  - Dial Pulsing
  - Ground Start
  - Ringer Injection
- Instrumentation
  - Multiplexers
  - Data Acquisition
  - Electronic Switching
  - I/O Subsystems
  - Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Aerospace
- Industrial Controls

### Description

The TS112 Multifunction Telecom switch combines a 350V Form A relay and an optocoupler in a single package. The relay uses optically coupled MOSFET technology to provide 1500V of input to output isolation. The efficient MOSFET switch and photovoltaic die use Clare's patented OptoMOS architecture. The optically coupled input uses highly efficient GaAlAs infrared LEDs. TS112N allows telecom circuit designers to combine two discrete functions, such as hook switch and ring detect, in a single component. The TS112's small package uses less space than traditional discrete component solutions.

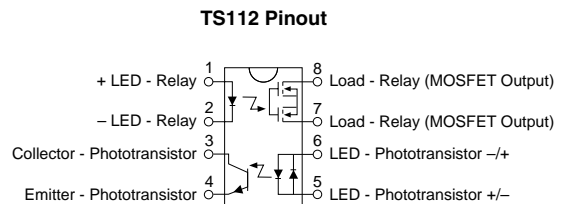
### Approvals

- UL Recognized: File Number Pending
- CSA Certified: File Number Pending
- BSI Certified: Pending

### Ordering Information

Part #	Description
TS112N	8 Pin SOIC (50/Tube)
TS112NTR	8 Pin SOIC Tape & Reel (1000/Reel)

### Pin Configuration



**Absolute Maximum Ratings (@ 25° C)**

Parameter	Min	Typ	Max	Units
Input Power Dissipation	-	-	150 <sup>1</sup>	mW
Input Control Current	-	-	100	mA
Peak (10ms)	-	-	1	A
Reverse Input Voltage	-	-	5	V
Total Power Dissipation	-	-	800 <sup>2</sup>	mW
Isolation Voltage Input to Output	1500	-	-	V <sub>RMS</sub>
Operational Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+125	°C
Soldering Temperature (10 Seconds Max.)			+220	°C

<sup>1</sup> Derate Linearly 1.33 mw/°C

<sup>2</sup> Derate Linearly 6.67 mw/°C

*Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and effect its reliability.*

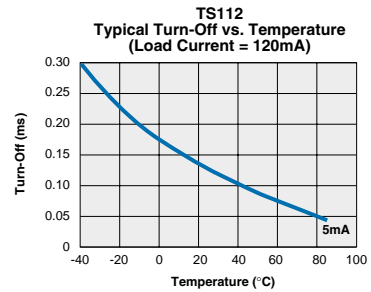
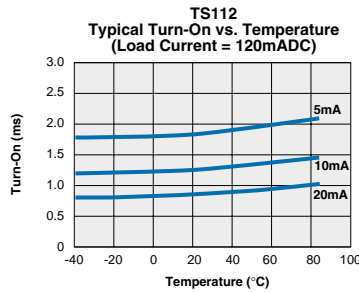
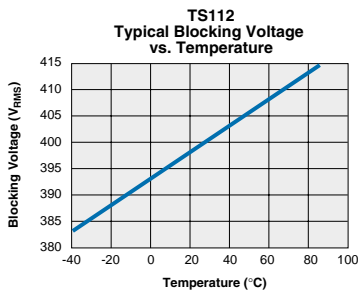
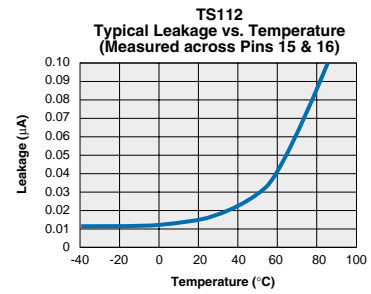
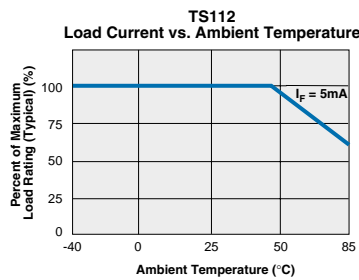
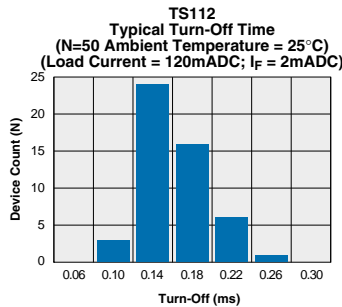
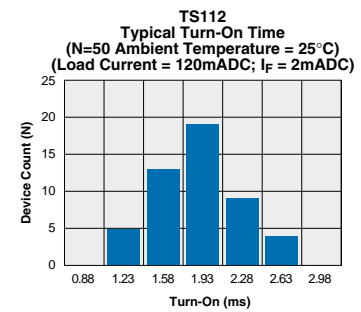
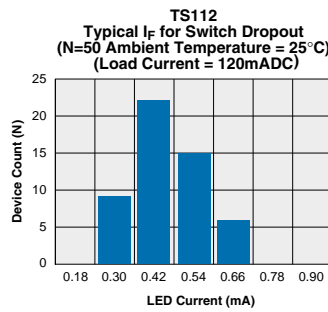
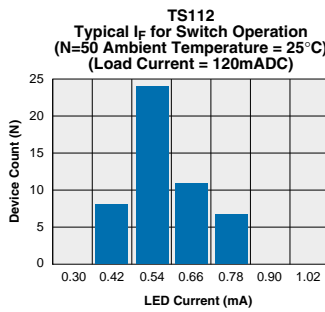
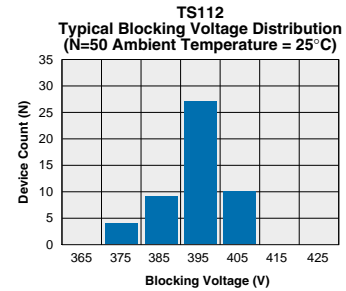
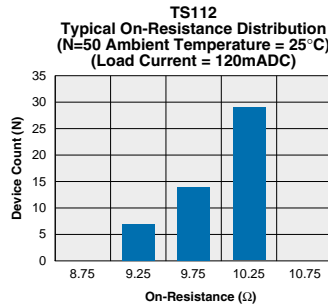
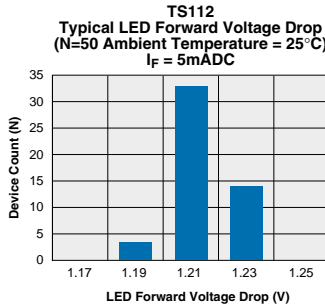
**Electrical Characteristics**

Parameter	Conditions	Symbol	Min	Typ	Max	Units
<b>Relay Portion (Pins 7, 8)</b>						
<b>Output Characteristics @ 25°C</b>						
Load Voltage (Peak)	-	V <sub>L</sub>	-	-	350	V
Load Current (Continuous)	-	I <sub>L</sub>	-	-	120	mA
Peak Load Current	10ms	I <sub>LPK</sub>	-	-	350	mA
On-Resistance	I <sub>L</sub> =120mA	R <sub>ON</sub>	-	15	20	Ω
Off-State Leakage Current	V <sub>L</sub> =350V	I <sub>LEAK</sub>	-	-	1	μA
<b>Switching Speeds</b>						
Turn-On	I <sub>F</sub> =5mA, V <sub>L</sub> =10V	T <sub>ON</sub>	-	-	3	ms
Turn-Off	I <sub>F</sub> =5mA, V <sub>L</sub> =10V	T <sub>OFF</sub>	-	-	3	ms
Output Capacitance	50V; f=1MHz	C <sub>OUT</sub>	-	25	-	pF
Load Current Limit		I <sub>CL</sub>	-	-	-	mA
<b>Relay Portion (Pins 1, 2)</b>						
<b>Input Characteristics @ 25°C</b>						
Input Control Current	I <sub>L</sub> =120mA	I <sub>F</sub>	2	-	50	mA
Input Dropout Current	-	I <sub>F</sub>	0.4	0.7	-	mA
Input Voltage Drop	I <sub>F</sub> =5mA	V <sub>F</sub>	0.9	1.2	1.4	V
Reverse Input Voltage	-	V <sub>R</sub>	-	-	5	V
Reverse Input Current	V <sub>R</sub>	I <sub>R</sub>	-	-	10	μA
<b>Detector Portion (Pins 3, 4)</b>						
<b>Output Characteristics @ 25°C</b>						
Phototransistor Blocking Voltage	I <sub>C</sub> =10μA	BV <sub>CEO</sub>	20	50	-	V
Phototransistor Output Current	V <sub>CE</sub> =5V, I <sub>F</sub> =0mA	I <sub>CEO</sub>	-	50	500	nA
Saturation Voltage	I <sub>C</sub> =2mA, I <sub>F</sub> =16mA	V <sub>SAT</sub>	-	0.3	0.5	V
Current Transfer Ratio	I <sub>F</sub> =6mA, V <sub>CE</sub> =0.5V	CTR	33	100	-	%

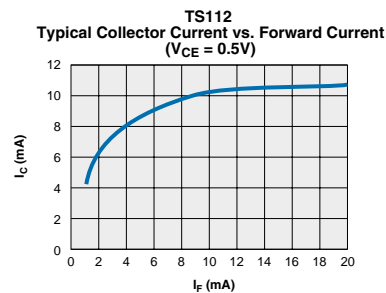
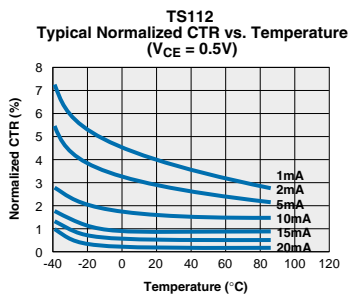
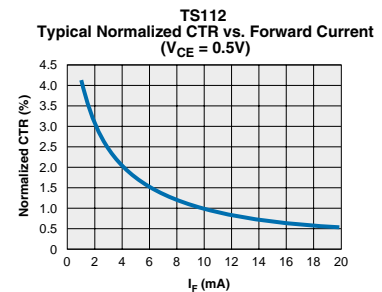
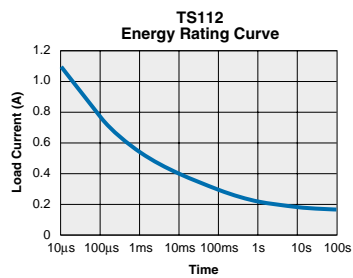
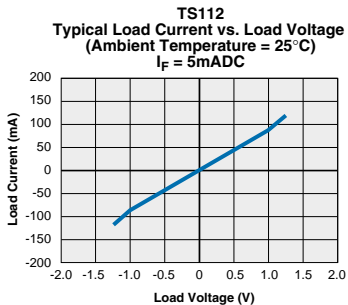
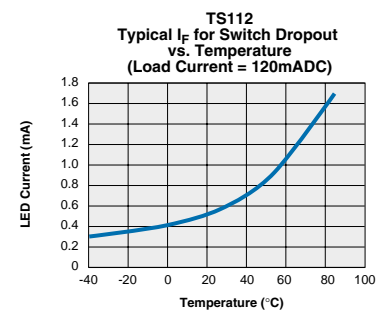
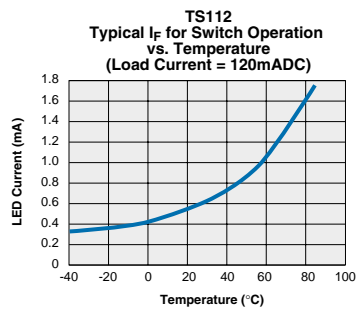
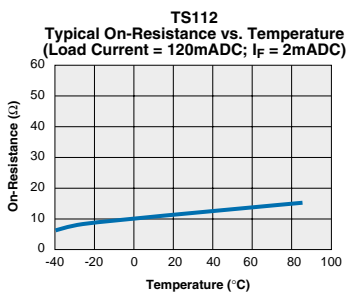
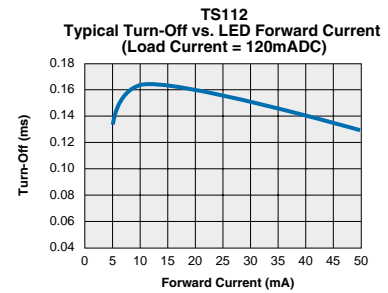
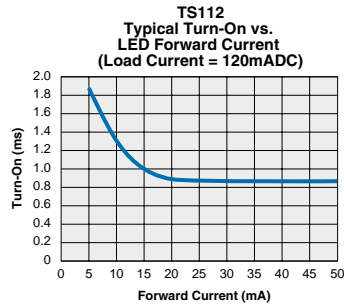
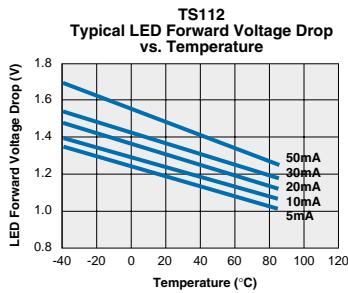
**Electrical Characteristics (continued)**

Parameter	Conditions	Symbol	Min	Typ	Max	Units
<b>Detector Portion (Pins 5, 6)</b>						
<b>Input Characteristics @ 25°C</b>						
Input Control Current	$I_C=2\text{mA}, V_{CE}=0.5\text{V}$	$I_F$	6	2	100	mA
Input Voltage Drop	$I_F=5\text{mA}$	$V_F$	0.9	1.2	1.4	V
Input Current (Detector must be off)	$I_C=1\mu\text{A}, V_{CE}=5\text{V}$	$I_F$	5	25	-	$\mu\text{A}$
Input to Output Capacitance (Relay Only)	-	$C_{I/O}$	-	0.8	-	pF
Capacitance Input to Output	-	-	-	3	-	pF
Input to Output Isolation	-	$V_{I/O}$	1500	-	-	$V_{\text{RMS}}$

PERFORMANCE DATA\*



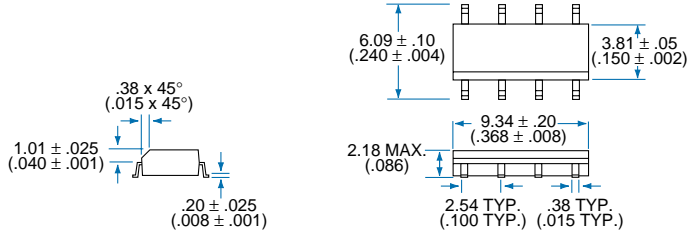
The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

**PERFORMANCE DATA\***


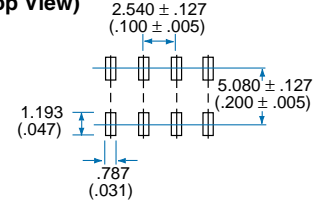
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Mechanical Dimensions

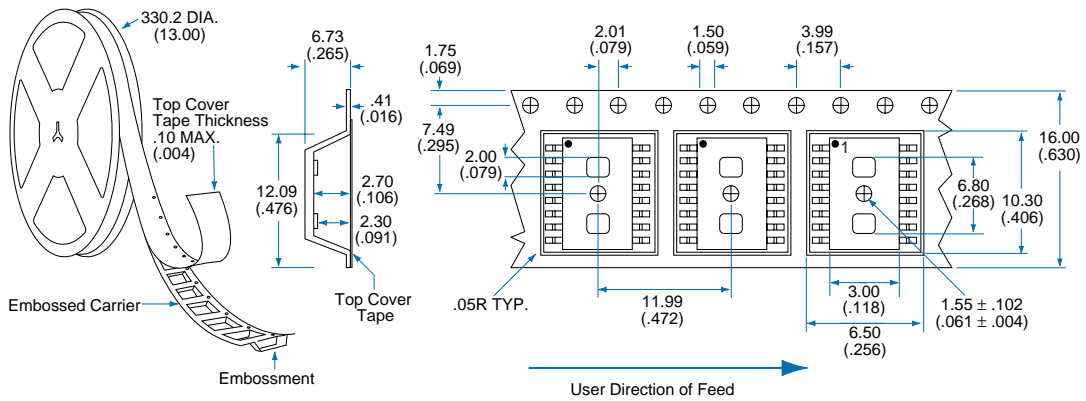
8 Pin SOIC Narrow ("N" Suffix)



PC Board Pattern (Top View)



Tape and Reel Packaging for 8 and 16 Pin Narrow SOIC Package



Dimensions  
 mm  
 (inches)



# CLARE

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